L Number	Hits	Search Text	DB	Time stamp
1	1337	SOI and CMOS and "p-type" and "n-type"	USPAT; US-PGPUB;	2002/06/25 14:01
2	2873	(/257/247) an (257/245) an (257/252) an	EPO; JPO; DERWENT; IBM_TDB USPAT;	2002/06/25
2	2873	((257/347) or (257/345) or (257/353) or (257/346) or (438/289)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	14:01
-	2	("6127702").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/25
1	4010	(yamazaki with shunpei).in.	USPĀT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/25
-	49	((yamazaki with shunpei).in.) and SOI	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/25
-	12	(("5210437") or ("4999682") or ("4959697") or ("5894137")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/26
-	2	("6218714").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/26
_	1308	(semiconductor with energy with laboratory).as.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/26
_	1308	(semiconductor adj energy adj laboratory).as.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/26
-	216	((semiconductor with energy with laboratory).as.) and (Fish).att.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/09/26
_	127	((semiconductor with energy with laboratory).as.) and (peabody).att.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/26
_	0	((semiconductor with energy with laboratory).as.) and (freedmon).att.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/26
-	36	<pre>(((semiconductor with energy with laboratory).as.) and (Fish).att.) and (locally)</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/26 10:06

f _	13	(((semiconductor with energy with	USPAT;	2001/09/26
_	13	laboratory).as.) and (peabody).att.) and	US-PGPUB;	10:11
		(locally)	EPO; JPO;	10.11
		(LOCALLY)	DERWENT;	
			IBM TDB	
	0	((((semiconductor with energy with	USPAT;	2001/09/26
_	"	laboratory).as.) and (Fish).att.) and	US-PGPUB;	10:12
		(locally)) and artifically	EPO; JPO;	10.12
		(locally)) and artifically	DERWENT;	
			IBM_TDB	2001/09/26
-	2		USPAT;	
		laboratory).as.) and (peabody).att.) and	US-PGPUB;	10:12
		(locally)) and artificially	EPO; JPO;	
			DERWENT;	
		l., , , , , , , , , , , , , , , , , , ,	IBM_TDB	0007/00/05
_	1308	((semiconductor adj energy) adj	USPAT;	2001/09/26
		laboratory).as.	US-PGPUB;	10:13
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	0		USPAT;	2001/09/26
		laboratory).as.) and (furguson).att.	ู้บริ-PGPUB;	10:14
			EPO; JPO;	
			DERWENT;	ļ
			IBM_TDB	
_	130	(((semiconductor adj energy) adj	USPAT;	2001/09/26
		laboratory).as.) and (nixxon or	US-PGPUB;	10:14
		nixon).att.	EPO; JPO;	1
			DERWENT;	
			IBM TDB	
_	217	(((semiconductor adj energy) adj	USPĀT;	2001/09/26
	1	laboratory).as.) and (fish or	US-PGPUB;	10:14
		richardson).att.	EPO; JPO;	
			DERWENT;	
			IBM TDB	ĺ
_	0	((((semiconductor adj energy) adj	USPAT;	2001/09/26
	l	laboratory).as.) and (nixxon or	US-PGPUB;	10:15
		nixon).att.) and (artifically)	EPO; JPO;	10.10
		mixon, acc., and (accitically)	DERWENT;	
			IBM TDB	, ,
	2	((((semiconductor adj energy) adj	USPAT;	2001/09/26
-	2		US-PGPUB;	10:15
		laboratory).as.) and (nixxon or nixon).att.) and artificially	EPO; JPO;	10.15
		nixon).acc.) and artificially	DERWENT;	
			1	
		1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1	IBM_TDB	2001/00/26
-	12		USPAT;	2001/09/26
		laboratory).as.) and (fish or	US-PGPUB;	10:15
	1	richardson).att.) and artificially	EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	